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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

Marking code: Q051

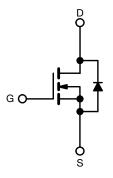
PRODUCT SUMMARY	
V _{DS} (V)	60
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0112
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.0160
I _D (A)	18
Configuration	Single

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912







N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 1212-8W
Lead (Pb)-free and halogen-free	SQS660CENW (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATINGS	$T_C = 25 ^{\circ}C$, unless	otherwise noted	d)		
PARAMETER	ARAMETER		LIMIT	UNIT	
Drain-source voltage	V _{DS}	60			
Gate-source voltage	V_{GS}	± 20	V		
Continuous drain current ^a	T _C = 25 °C	1	18		
	T _C = 125 °C	I _D	18		
Continuous source current (diode conduction) a		I _S	18	А	
Pulsed drain current ^b		I _{DM}	72		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	24.5		
Single pulse avalanche energy	L = U.1 MH	E _{AS}	30	mJ	
Maximum power dissipation	T _C = 25 °C	Б	62.5	14/	
	T _C = 125 °C	P_{D}	20	W	
Operating junction and storage temperature range Soldering recommendations (peak temperature) d, e		T _J , T _{stg}	-55 to +175		
			260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount c	R_{thJA}	81	°C/W
Junction-to-case (drain)		R_{thJC}	2.4	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8W is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static								
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = 250 μA	60	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$		1.5	2.0	2.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	μΑ	
Zero gate voltage drain current	I_{DSS}	V _{GS} = 0 V	V _{DS} = 60 V, T _J = 125 °C	-	-	50		
		V _{GS} = 0 V	V _{DS} = 60 V, T _J = 175 °C	-	-	150		
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	15	-	-	Α	
		V _{GS} = 10 V	I _D = 7 A	-	0.0091	0.0112		
5	_	V _{GS} = 10 V	I _D = 7 A, T _J = 125 °C	-	-	0.0175		
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 7 A, T _J = 175 °C	-	-	0.0207	Ω	
		V _{GS} = 4.5 V	I _D = 5 A	-	0.0129	0.0160	1	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 7 A	-	26	-	S	
Dynamic ^b				ı		l		
Input capacitance	C _{iss}			-	1363	1950		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	565	800	pF	
Reverse transfer capacitance	C _{rss}	_		-	22	31	1	
Total gate charge c	Qg			-	17.4	26		
Gate-source charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 30 \text{ V}, I_D = 4 \text{ A}$	-	4.8	-	nC	
Gate-drain charge ^c	Q _{gd}	_		-	1.1	-		
Gate resistance	R_g	f = 1 MHz		0.27	0.54	0.81	Ω	
Turn-on delay time c	t _{d(on)}			-	12	20		
Rise time ^c	t _r	V _{DD} =	$\approx 30 \text{ V}, \text{ R}_{\text{L}} = 7.5 \Omega$	-	4	10	ns	
Turn-off delay time ^c	t _{d(off)}		$I_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	20	35		
Fall time ^c	t _f	1		-	5	10	1	
Source-Drain Diode Ratings and Charact	eristic ^b							
Pulsed current ^a	I _{SM}			-	_	72	Α	
Forward voltage	V _{SD}	I _F = 7 A, V _{GS} = 0 V		-	0.8	1.1	V	
Body diode reverse recovery time	t _{rr}			-	27	55	ns	
Body diode reverse recovery charge	Q _{rr}			-	21	45	nC	
Reverse recovery fall time	t _a			-	14	-		
Reverse recovery rise time	t _b	_		-	13	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.4	-	Α	

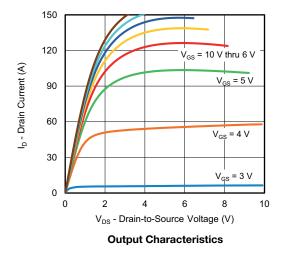
Notes

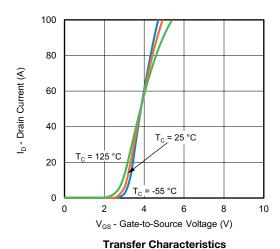
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

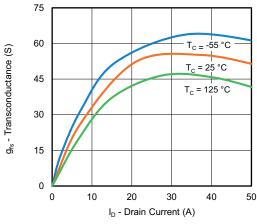
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

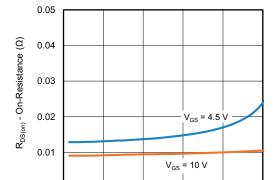


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)









30

0

0

15



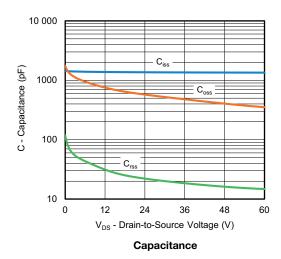
I_D - Drain Current (A)

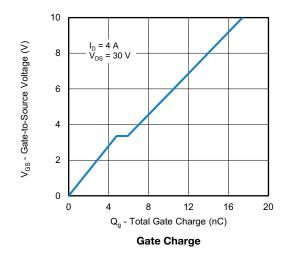
On-Resistance vs. Drain Current

45

60

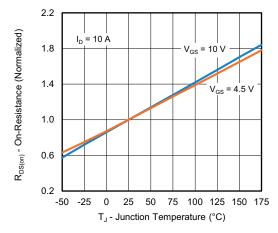
75



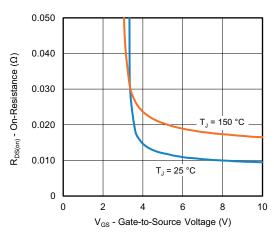




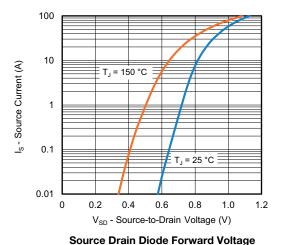
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



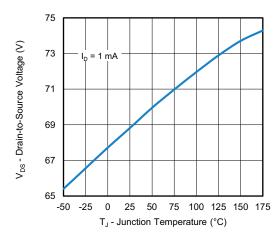
On-Resistance vs. Junction Temperature



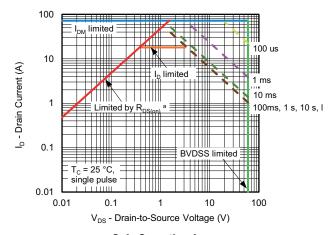
On-Resistance vs. Gate-to-Source Voltage



0.4
0.1
(2)
0.2
-0.5
-0.8
-1.1
-50 -25 0 25 50 75 100 125 150 175



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area

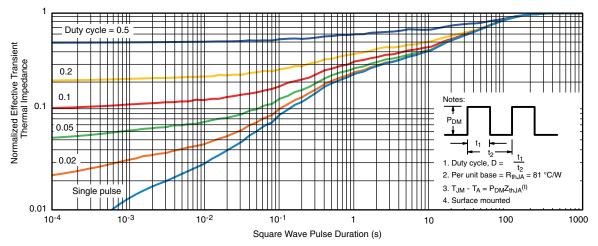
Note

a. V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

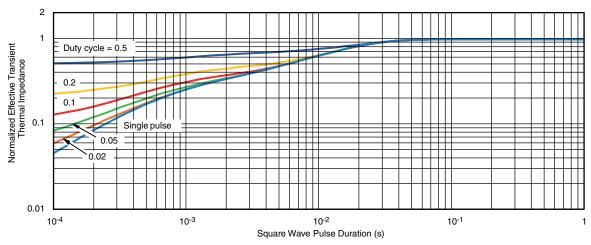
For technical questions, contact: automostechsu



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

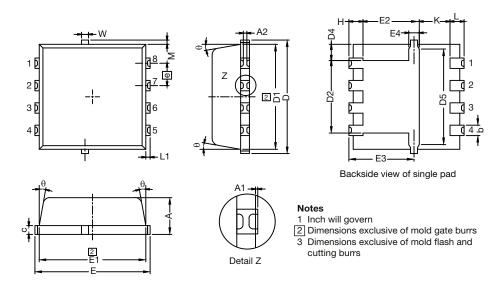
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63003.



PowerPAK® 1212-8W Case Outline



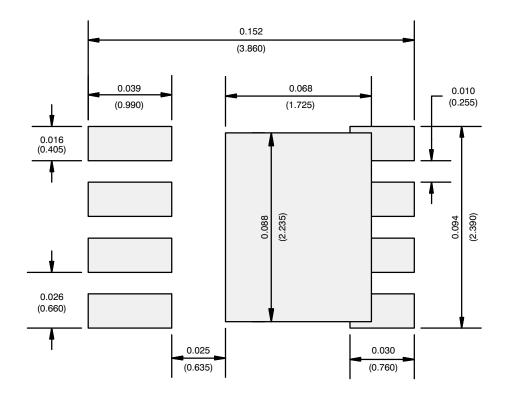
DIM.		MILLIMETERS			INCHES			
DIN.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1	0	-	0.05	0	-	0.002		
A2	0	-	0.13	0	-	0.005		
b	0.23	0.30	0.41	0.009	0.012	0.016		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	3.20	3.30	3.40	0.126	0.130	0.134		
D1	2.95	3.05	3.15	0.116	0.120	0.124		
D2	1.98	2.11	2.24	0.078	0.083	0.088		
D4		0.47 typ.			0.0185 typ.			
D5		2.3 typ.			0.090 typ.			
E	3.20	3.30	3.40	0.126	0.130	0.134		
E1	2.95	3.05	3.15	0.116	0.120	0.124		
E2	1.47	1.60	1.73	0.058	0.063	0.068		
E3	1.75	1.85	1.98	0.069	0.073	0.078		
E4		0.34 typ.	/p. 0.013 typ		0.013 typ.			
е		0.65 BSC.		0.026 BSC				
K		0.86 typ.		0.034 typ.				
Н	0.30	0.41	0.51	0.012	0.016	0.020		
L	0.30	0.43	0.56	0.012	0.017	0.022		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
М	0.125 typ.			0.005 typ.				

DWC: 6020

DWG: 6032



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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